

具有 $\pm 8\text{kV}$ IEC ESD 保护功能的 THVD1520 10Mbps RS-485 收发器

1 特性

- 符合或超出 TIA/EIA-485A 标准要求
- 4.5V 至 5.5V 电源电压
- 10Mbps 半双工 RS-422/RS-485
- 总线 I/O 保护
 - $\pm 16\text{kV}$ HBM ESD
 - $\pm 8\text{kV}$ IEC 61000-4-2 接触放电
 - $\pm 8\text{kV}$ IEC 61000-4-2 空气间隙放电
 - $\pm 4\text{kV}$ IEC 61000-4-4 快速瞬变脉冲
- 工业工作温度范围: -40°C 至 125°C
- 用于噪声抑制的较大接收器滞后
- 低功耗
 - 低待机电源电流: $< 1\mu\text{A}$
 - 运行期间静态电流: $< 840\mu\text{A}$
- 适用于热插拔功能的无干扰上电/断电
- 开路、短路和空闲总线失效防护
- 1/8 单位负载 (多达 256 个总线节点)

2 应用

- 工厂自动化和控制
- 楼宇自动化
- HVAC 系统
- 视频监控
- 智能仪表

3 说明

THVD1520 是适用于工业应用的强大半双工 RS-485 收发器。这些总线引脚可耐受高级别的 IEC 接触放电 ESD 事件, 因此无需使用其他系统级保护组件。

该器件由 5V 单电源供电。总线引脚具备宽共模电压范围和低输入泄漏, 因此 THVD1520 适用于长电缆上的多点应用。

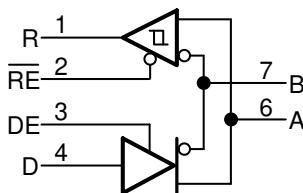
THVD1520 采用可实现快插兼容性的业界通用 8 引脚 SOIC 封装。该器件的额定温度范围为 -40°C 至 125°C 。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
THVD1520	SOIC (8)	4.90mm × 3.91mm

(1) 如需了解所有可用封装, 请参阅产品说明书末尾的可订购产品附录。

简化原理图



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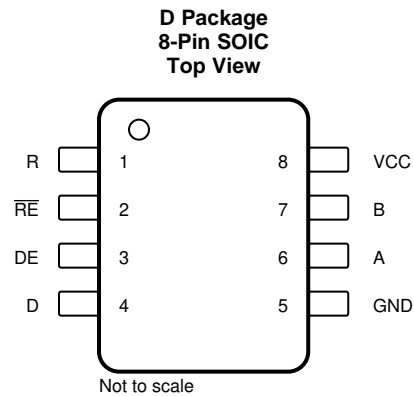
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4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

日期	修订版本	说明
2019 年 10 月	*	初始发行版。

5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
R	1	Digital output	Receive data output
$\overline{\text{RE}}$	2	Digital input	Receiver enable, active low (internal 5-M Ω pull-up)
DE	3	Digital input	Driver enable, active high (internal 5-M Ω pull-down)
D	4	Digital input	Driver data input (internal 5-M Ω pull-up)
GND	5	Ground	Device ground
A	6	Bus input/output	Bus I/O port, A (complementary to B)
B	7	Bus input/output	Bus I/O port, B (complementary to A)
V _{CC}	8	Power	5-V supply

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage	−0.5	7	V
V _L	Input voltage at any logic pin (D, DE or RE)	−0.3	5.7	V
V _A , V _B	Voltage at A or B inputs, as differential or common-mode with respect to GND	−18	18	V
I _O	Receiver output current	−24	24	mA
T _J	Junction temperature		170	°C
T _{STG}	Storage temperature	−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	Bus terminals and GND	±16,000
			All other pins	±4,000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾		±1,500

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 ESD Ratings [IEC]

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	IEC 61000-4-2 ESD (Contact Discharge), bus terminals and GND	±8,000	V
		IEC 61000-4-2 ESD (Air-Gap Discharge), bus terminals and GND	±8,000	
		IEC 61000-4-4 EFT (Fast transient or burst), bus terminals and GND	±4,000	

6.4 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	4.5	5	5.5	V
V_{ID}	Differential input voltage	–12		12	V
V_I	Input voltage at any bus terminal ⁽¹⁾	–7		12	V
V_{IH}	High-level input voltage (driver, driver-enable, and receiver-enable inputs)	2		V_{CC}	V
V_{IL}	Low-level input voltage (driver, driver-enable, and receiver-enable inputs)	0		0.8	V
I_O	Output current	Driver		60	mA
		Receiver		8	
R_L	Differential load resistance	54	60		Ω
$1/t_{UI}$	Signaling rate			10	Mbps
T_J	Junction temperature	–40		150	°C
$T_A^{(2)}$	Operating ambient temperature	–40		125	°C

- (1) The algebraic convention in which the least positive (most negative) limit is designated as minimum is used in this data sheet.
- (2) Operation is specified for internal (junction) temperatures upto 150°C. Self-heating due to internal power dissipation should be considered for each application. Maximum junction temperature is internally limited by the thermal shutdown (TSD) circuit which disables the device when the junction temperature reaches 170°C.

6.5 Thermal Information

THERMAL METRIC ⁽¹⁾		THVD1520	UNIT
		D (SOIC)	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	125.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	67.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	68.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	20.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	67.8	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.6 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Driver							
$ V_{OD} $	Driver differential-output voltage magnitude	V_{test} from -7 to $+12$ V	See 图 7	1.5	2.5	V	
		$R_L = 54\ \Omega$ (RS-485), $C_L = 50$ pF	See 图 8	1.5	2.5		
		$R_L = 100\ \Omega$ (RS-422), $C_L = 50$ pF		2	3		
$\Delta V_{OD} $	Change in magnitude of driver differential-output voltage	$R_L = 54\ \Omega$ or $100\ \Omega$, $C_L = 50$ pF	See 图 8	-50		50	mV
$V_{OC(SS)}$	Steady-state common-mode output voltage	$R_L = 54\ \Omega$ or $100\ \Omega$, $C_L = 50$ pF	See 图 8	1	$V_{CC} / 2$	3	V
ΔV_{OC}	Change in differential driver common-mode output voltage			-50		50	mV
$V_{OC(PP)}$	Peak-to-peak driver common-mode output voltage				220		mV
$ I_{OS} $	Driver short-circuit output current	$DE = V_{CC}$, $-7\text{ V} \leq [V_A \text{ or } V_B] \leq 12\text{ V}$, or A pin shorted to B pin				150	mA
C_{OD}	Differential output capacitance				8		pF
Receiver							
I_I	Bus input current (driver disabled)	$DE = 0\text{ V}$, $V_{CC} = 0\text{ V}$ or 5.5 V	$V_I = 12\text{ V}$		75	110	μA
			$V_I = -7\text{ V}$	-90	-70		
R_A, R_B	Bus input impedance	$V_A = -7\text{ V}$, $V_B = 12\text{ V}$ and $V_A = 12\text{ V}$, $V_B = -7\text{ V}$	See 图 12	96			k Ω
V_{IT+}	Positive-going receiver differential-input voltage threshold				-90	-50	mV
V_{IT-}	Negative-going receiver differential-input voltage threshold			-200	-150		mV
$V_{HYS}^{(1)}$	Receiver differential-input voltage threshold hysteresis ($V_{IT+} - V_{IT-}$)			40	60		mV
V_{OH}	Receiver high-level output voltage	$I_{OH} = -8\text{ mA}$		4	$V_{CC} - 0.3$		V
V_{OL}	Receiver low-level output voltage	$I_{OL} = 8\text{ mA}$			0.2	0.4	V
I_{OZ}	Receiver high-impedance output current	$V_O = 0\text{ V}$ or V_{CC} , $\overline{RE} = V_{CC}$		-1		1	μA
I_{OSR}	Receiver output short-circuit current	$\overline{RE} = 0$, $DE = 0$	See 图 13			95	mA
Logic							
I_{IN}	Input current (D, DE, \overline{RE})			-2.5		2.5	μA
Supply							
I_{CC}	Supply current (quiescent)	Driver and receiver enabled	$DE = V_{CC}$, $\overline{RE} = 0$, no load		600	840	μA
		Driver enabled, receiver disabled	$DE = V_{CC}$, $\overline{RE} = V_{CC}$, no load		440	580	
		Driver disabled, receiver enabled	$DE = 0$, $\overline{RE} = 0$, no load		530	680	
		Driver and receiver disabled	$DE = 0$, $\overline{RE} = V_{CC}$, no load		0.1	1	

(1) Under any specific conditions, V_{IT+} is specified to be at least V_{HYS} higher than V_{IT-} .

6.7 Power Dissipation Characteristics

PARAMETER			TEST CONDITIONS	VALUE	UNIT
PD	Power dissipation, driver and receiver enabled, $V_{CC} = 5.5\text{ V}$, $T_A = 125^\circ\text{C}$, 50% duty cycle square-wave signal at maximum signaling rate	Unterminated	$R_L = 300\ \Omega$, $C_L = 50\text{ pF}$	100	mW
		RS-422 load	$R_L = 100\ \Omega$, $C_L = 50\text{ pF}$	135	
		RS-485 load	$R_L = 54\ \Omega$, $C_L = 50\text{ pF}$	190	

6.8 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Driver							
t _r , t _f	Driver differential output rise and fall times		See Figure 9	10	17	30	ns
t _{PHL} , t _{PLH}	Driver propagation delay		See Figure 9		20	35	ns
t _{SK(P)}	Driver pulse skew, t _{PHL} – t _{PLH}		See Figure 9		0.8	4	ns
t _{PHZ} , t _{PLZ}	Driver disable time		See Figure 10 and Figure 11		25	100	ns
t _{PHZ} , t _{PLZ}	Driver enable time	Receiver enabled	See Figure 10 and Figure 11		25	100	ns
		Receiver disabled	See Figure 10 and Figure 11		1.5	3	μs
Receiver							
t _r , t _f	Receiver output rise and fall times		See Figure 14		5	15	ns
t _{PHL} , t _{PLH}	Receiver propagation delay time		See Figure 14		50	95	ns
t _{SK(P)}	Receiver pulse skew, t _{PHL} – t _{PLH}		See Figure 14		3	15	ns
t _{PHZ} , t _{PLZ}	Receiver disable time		See Figure 15		15	30	ns
t _{PZL(1)} , t _{PZH(1)} t _{PZL(2)} , t _{PZH(2)}	Receiver enable time	Driver enabled	See Figure 15		25	170	ns
		Driver disabled	See Figure 16		1	5	μs

6.9 Typical Characteristics

$V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

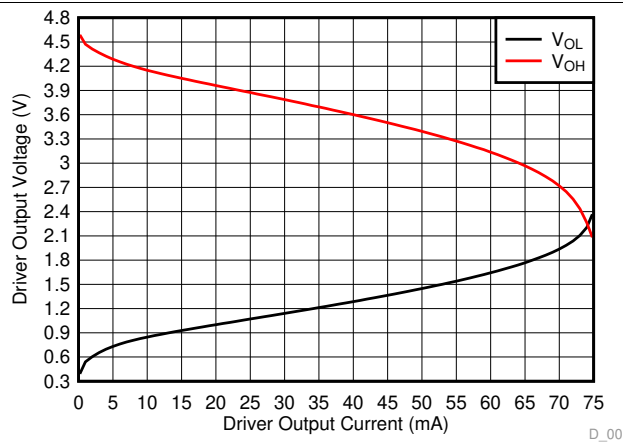


图 1. Driver Output Voltage vs Driver Output Current

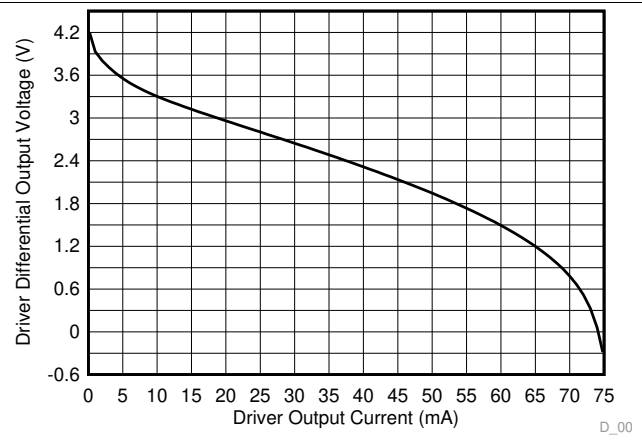


图 2. Driver Differential Output Voltage vs Driver Output Current

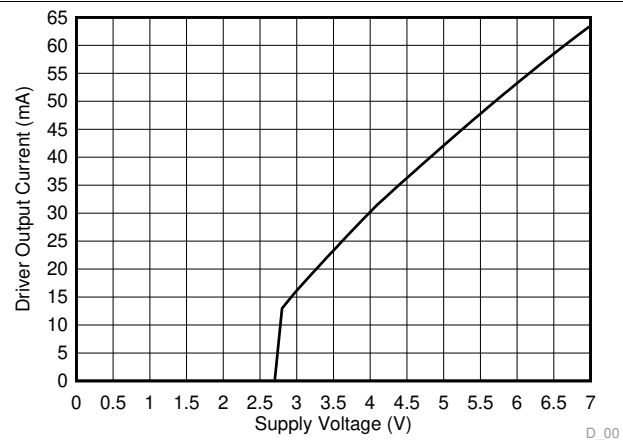


图 3. Driver Output Current vs Supply Voltage

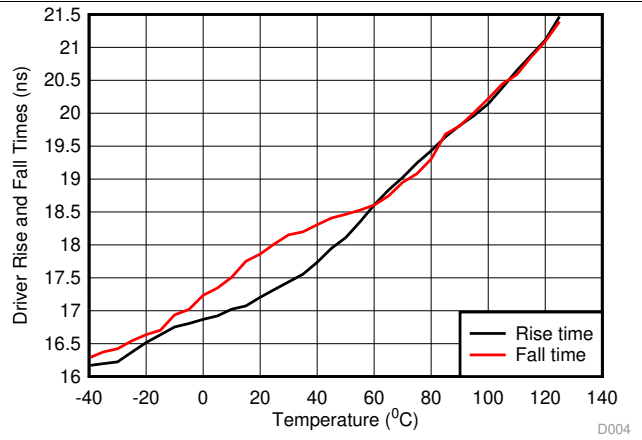


图 4. Driver Rise or Fall Time vs Temperature

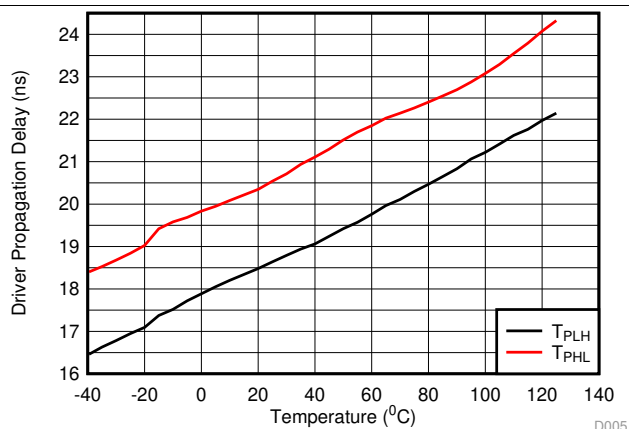
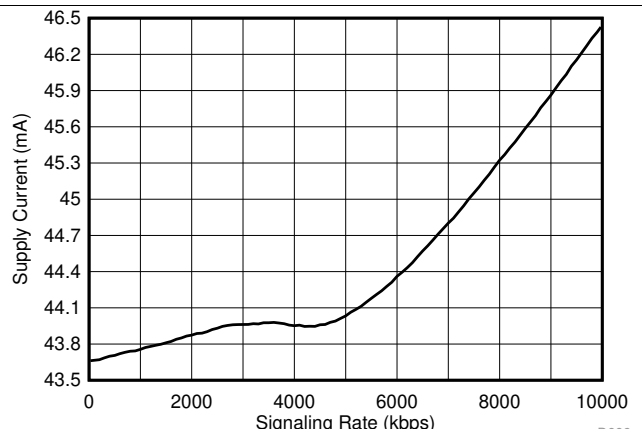


图 5. Driver Propagation Delay vs Temperature



50% duty cycle square-wave
 $R_L = 54\ \Omega$ $C_L = 50\text{ pF}$ $DE = V_{CC}, \overline{RE} = GND$

图 6. Supply Current vs Signaling Rate

7 Parameter Measurement Information

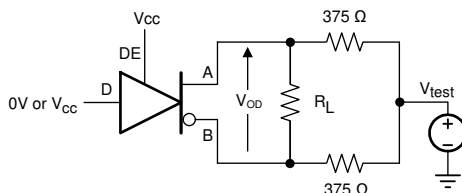


图 7. Measurement of Driver Differential Output Voltage With Common-Mode Load



图 8. Measurement of Driver Differential and Common-Mode Output With RS-485 Load

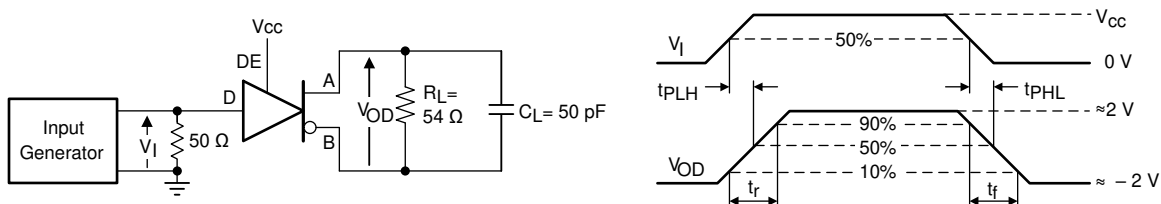


图 9. Measurement of Driver Differential Output Rise and Fall Times and Propagation Delays

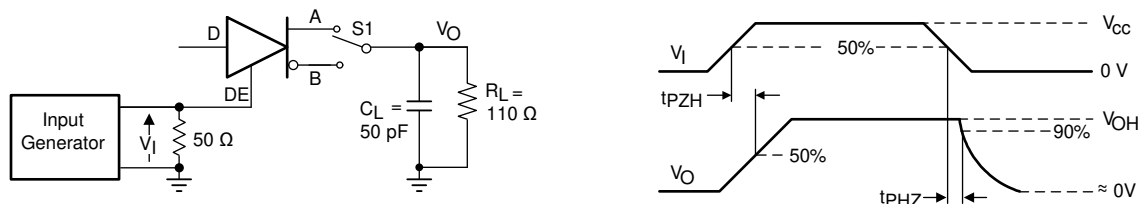


图 10. Measurement of Driver Enable and Disable Times With Active High Output and Pull-Down Load

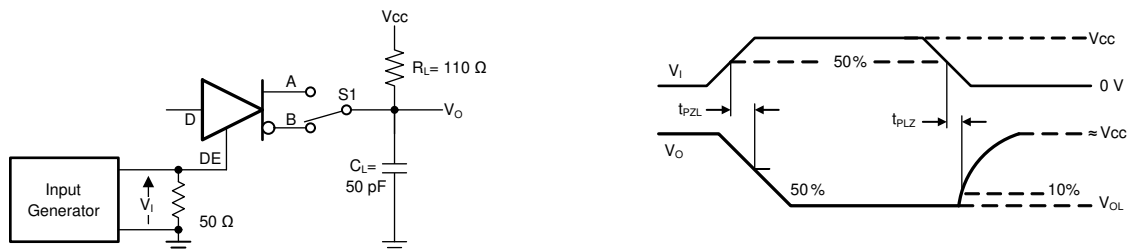


图 11. Measurement of Driver Enable and Disable Times With Active Low Output and Pull-up Load

Parameter Measurement Information (接下页)

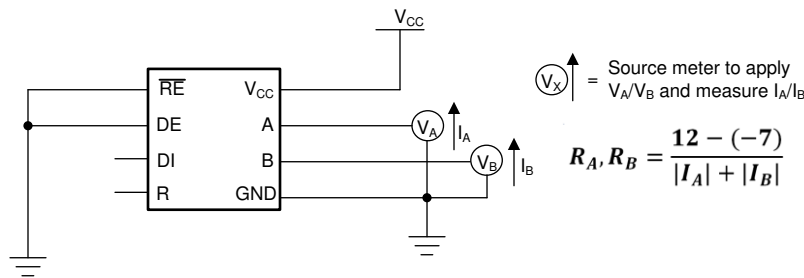


图 12. Measurement of Bus Impedance

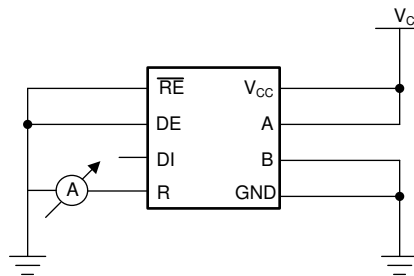


图 13. Measurement of Receiver Output Short Circuit Current

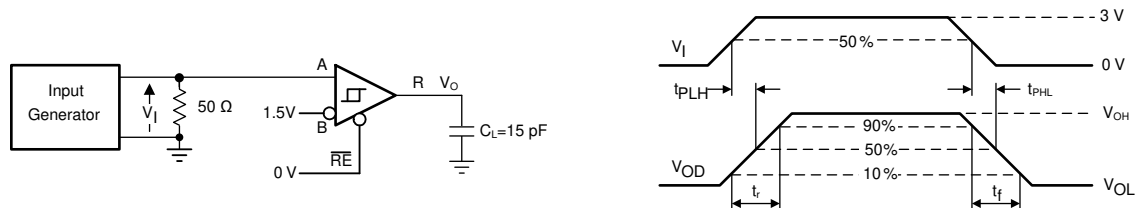


图 14. Measurement of Receiver Output Rise and Fall Times and Propagation Delays

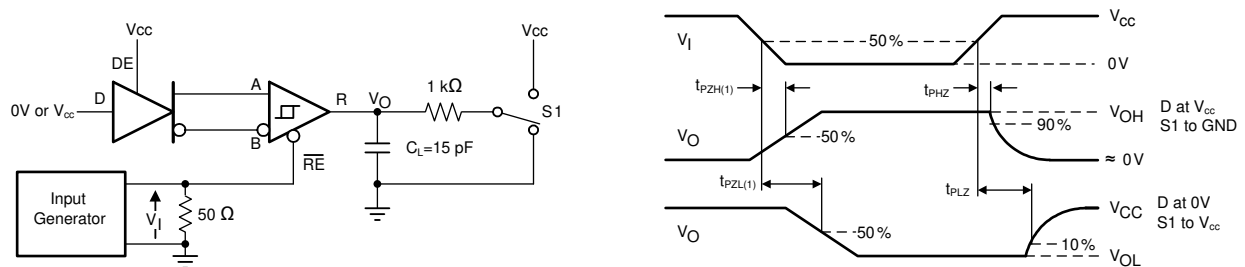


图 15. Measurement of Receiver Enable/Disable Times With Driver Enabled

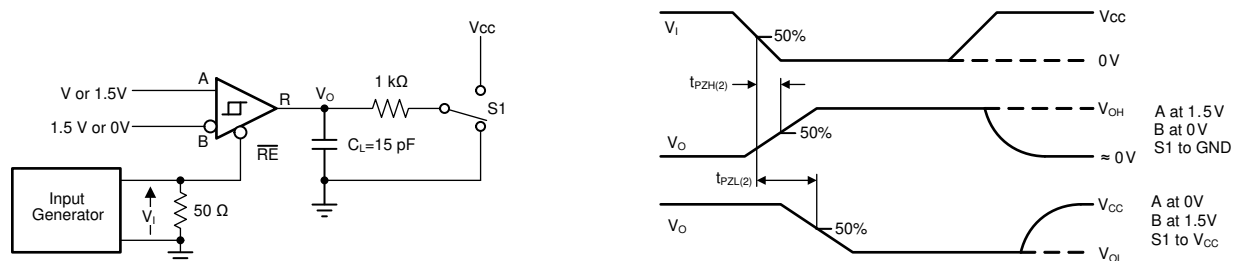


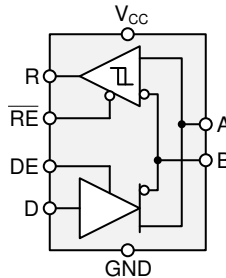
图 16. Measurement of Receiver Enable Times With Driver Disabled

8 Detailed Description

8.1 Overview

The THVD1520 is a low-power, half-duplex RS-485 transceiver suitable for data transmission up to 10 Mbps.

8.2 Functional Block Diagrams



8.3 Feature Description

Internal ESD protection circuits protect the transceiver against Electrostatic Discharges (ESD) according to IEC 61000-4-2 of up to ± 8 kV (contact discharge), ± 8 kV (air gap discharge) and against electrical fast transients (EFT) according to IEC 61000-4-4 of up to ± 4 kV.

8.4 Device Functional Modes

When the driver enable pin, DE, is logic high, the differential outputs A and B follow the logic states at data input D. A logic high at D causes A to turn high and B to turn low. In this case, the differential output voltage defined as $V_{OD} = V_A - V_B$ is positive. When D is low, the output states reverse, B turns high, A becomes low, and V_{OD} is negative.

When DE is low, both outputs turn high-impedance. In this condition the logic state at D is irrelevant. The DE pin has an internal pull-down resistor to ground, thus when left open the driver is disabled (high-impedance) by default. The D pin has an internal pull-up resistor to V_{CC} , thus, when left open while the driver is enabled, output A turns high and B turns low.

表 1. Driver Function Table

INPUT	ENABLE	OUTPUTS		FUNCTION
D	DE	A	B	
H	H	H	L	Actively drive bus high
L	H	L	H	Actively drive bus low
X	L	Z	Z	Driver disabled
X	OPEN	Z	Z	Driver disabled by default
OPEN	H	H	L	Actively drive bus high by default

When the receiver enable pin, \overline{RE} , is logic low, the receiver is enabled. When the differential input voltage defined as $V_{ID} = V_A - V_B$ is positive and higher than the positive input threshold, V_{IT+} , the receiver output, R, turns high. When V_{ID} is negative and lower than the negative input threshold, V_{IT-} , the receiver output, R, turns low. If V_{ID} is between V_{IT+} and V_{IT-} , the output is indeterminate.

When \overline{RE} is logic high or left open, the receiver output is high-impedance and the magnitude and polarity of V_{ID} are irrelevant. Internal biasing of the receiver inputs causes the output to go failsafe-high when the transceiver is disconnected from the bus (open-circuit), the bus lines are shorted (short-circuit), or the bus is not actively driven (idle bus).

表 2. Receiver Function Table

DIFFERENTIAL INPUT	ENABLE	OUTPUT	FUNCTION
$V_{ID} = V_A - V_B$	\overline{RE}	R	
$V_{IT+} < V_{ID}$	L	H	Receive valid bus high
$V_{IT-} < V_{ID} < V_{IT+}$	L	?	Indeterminate bus state
$V_{ID} < V_{IT-}$	L	L	Receive valid bus low
X	H	Z	Receiver disabled
X	OPEN	Z	Receiver disabled by default
Open-circuit bus	L	H	Fail-safe high output
Short-circuit bus	L	H	Fail-safe high output
Idle (terminated) bus	L	H	Fail-safe high output

9 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The THVD1520 is a half-duplex RS-485 transceiver commonly used for asynchronous data transmissions. The driver and receiver enable pins allow for the configuration of different operating modes.

9.2 Typical Application

An RS-485 bus consists of multiple transceivers connecting in parallel to a bus cable. To eliminate line reflections, each cable end is terminated with a termination resistor, R_T , whose value matches the characteristic impedance, Z_0 , of the cable. This method, known as parallel termination, allows for higher data rates over longer cable length.

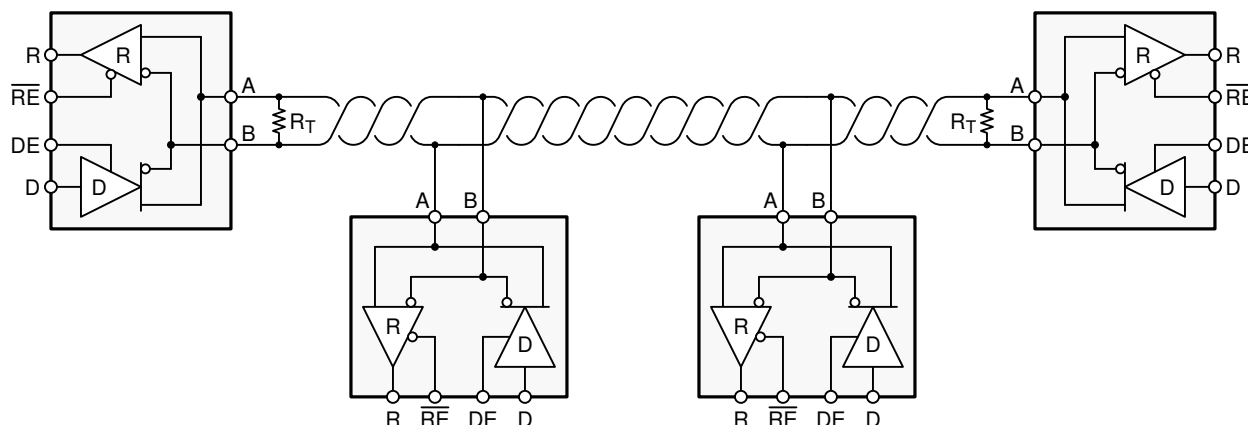


图 17. Typical RS-485 Network With Half-Duplex Transceivers

9.2.1 Design Requirements

RS-485 is a robust electrical standard suitable for long-distance networking that may be used in a wide range of applications with varying requirements, such as distance, data rate, and number of nodes.

9.2.1.1 Data Rate and Bus Length

There is an inverse relationship between data rate and cable length, which means the higher the data rate, the shorter the cable length; and conversely, the lower the data rate, the longer the cable length. While most RS-485 systems use data rates between 10 kbps and 100 kbps, some applications require data rates up to 250 kbps at distances of 4000 feet and longer. Longer distances are possible by allowing for small signal jitter of up to 5 or 10%.

Typical Application (接下页)

9.2.1.2 Stub Length

When connecting a node to the bus, the distance between the transceiver inputs and the cable trunk, known as the stub, should be as short as possible. Stubs present a non-terminated piece of bus line which can introduce reflections as the length of the stub increases. As a general guideline, the electrical length, or round-trip delay, of a stub should be less than one-tenth of the rise time of the driver, thus giving a maximum physical stub length as shown in 公式 1.

$$L_{(\text{STUB})} \leq 0.1 \times t_r \times v \times c$$

where

- t_r is the 10/90 rise time of the driver
- c is the speed of light (3×10^8 m/s)
- v is the signal velocity of the cable or trace as a factor of c

(1)

9.2.1.3 Bus Loading

The RS-485 standard specifies that a compliant driver must be able to driver 32 unit loads (UL), where 1 unit load represents a load impedance of approximately 12 kΩ. Because the THVD1520 consists of 1/8 UL transceivers, connecting up to 256 receivers to the bus is possible.

9.2.1.4 Receiver Failsafe

The differential receivers of the THVD1520 are *failsafe* to invalid bus states caused by the following:

- Open bus conditions, such as a disconnected connector
- Shorted bus conditions, such as cable damage shorting the twisted-pair together
- Idle bus conditions that occur when no driver on the bus is actively driving

In any of these cases, the differential receiver will output a failsafe logic high state so that the output of the receiver is not indeterminate.

Receiver failsafe is accomplished by offsetting the receiver thresholds such that the *input indeterminate* range does not include zero volts differential. In order to comply with the RS-422 and RS-485 standards, the receiver output must output a high when the differential input V_{ID} is more positive than 200 mV, and must output a low when V_{ID} is more negative than -200 mV. The receiver parameters which determine the failsafe performance are V_{IT+} , V_{IT-} , and V_{HYS} (the separation between V_{IT+} and V_{IT-}). As shown in the table, differential signals more negative than -200 mV will always cause a low receiver output, and differential signals more positive than 200 mV will always cause a high receiver output.

When the differential input signal is close to zero, it is still above the V_{IT+} threshold, and the receiver output will be high. Only when the differential input is more than V_{HYS} below V_{IT+} will the receiver output transition to a low state. Therefore, the noise immunity of the receiver inputs during a bus fault conditions includes the receiver hysteresis value, V_{HYS} , as well as the value of V_{IT+} .

Typical Application (接下页)

9.2.1.5 Transient Protection

The bus pins of the THVD1520 transceiver family include on-chip ESD protection against ± 16 -kV HBM and ± 8 -kV IEC 61000-4-2 contact discharge. The International Electrotechnical Commission (IEC) ESD test is far more severe than the HBM ESD test. The 50% higher charge capacitance, $C_{(S)}$, and 78% lower discharge resistance, $R_{(D)}$, of the IEC model produce significantly higher discharge currents than the HBM model.

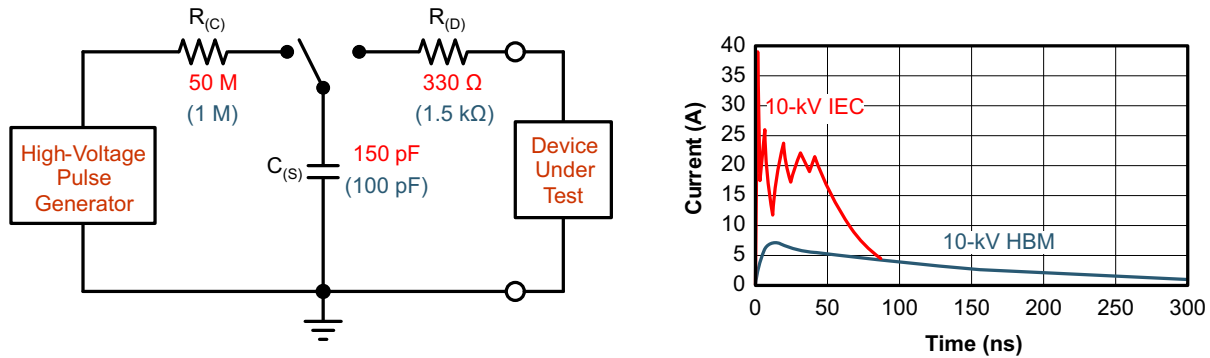


图 18. HBM and IEC ESD Models and Currents in Comparison (HBM Values in Parenthesis)

The on-chip implementation of IEC ESD protection significantly increases the robustness of equipment. Common discharge events occur because of human contact with connectors and cables. Designers may choose to implement protection against longer duration transients, typically referred to as surge transients.

EFTs are generally caused by relay-contact bounce or the interruption of inductive loads. Surge transients often result from lightning strikes (direct strike or an indirect strike which induce voltages and currents), or the switching of power systems, including load changes and short circuit switching. These transients are often encountered in industrial environments, such as factory automation and power-grid systems.

图 19 compares the pulse-power of the EFT and surge transients with the power caused by an IEC ESD transient. The left hand diagram shows the relative pulse-power for a 0.5-kV surge transient and 4-kV EFT transient, both of which dwarf the 10-kV ESD transient visible in the lower-left corner. 500-V surge transients are representative of events that may occur in factory environments in industrial and process automation.

The right hand diagram shows the pulse-power of a 6-kV surge transient, relative to the same 0.5-kV surge transient. 6-kV surge transients are most likely to occur in power generation and power-grid systems.

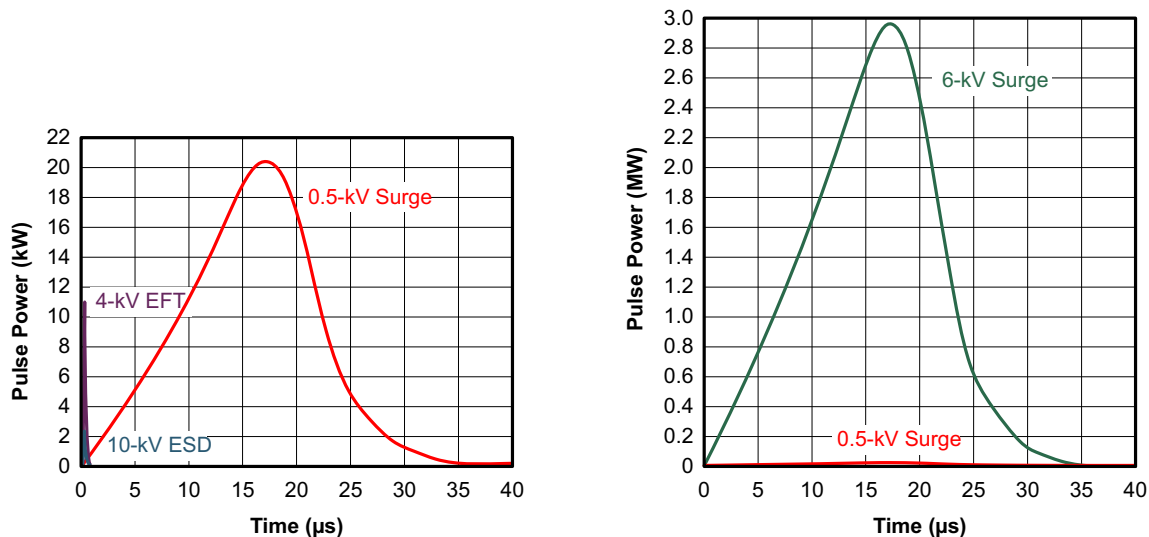


图 19. Power Comparison of ESD, EFT, and Surge Transients

Typical Application (接下页)

In the event of surge transients, high-energy content is characterized by long pulse duration and slow decaying pulse power. The electrical energy of a transient that is dumped into the internal protection cells of a transceiver is converted into thermal energy, which heats and destroys the protection cells, thus destroying the transceiver. 图 20 shows the large differences in transient energies for single ESD, EFT, surge transients, and an EFT pulse train that is commonly applied during compliance testing.

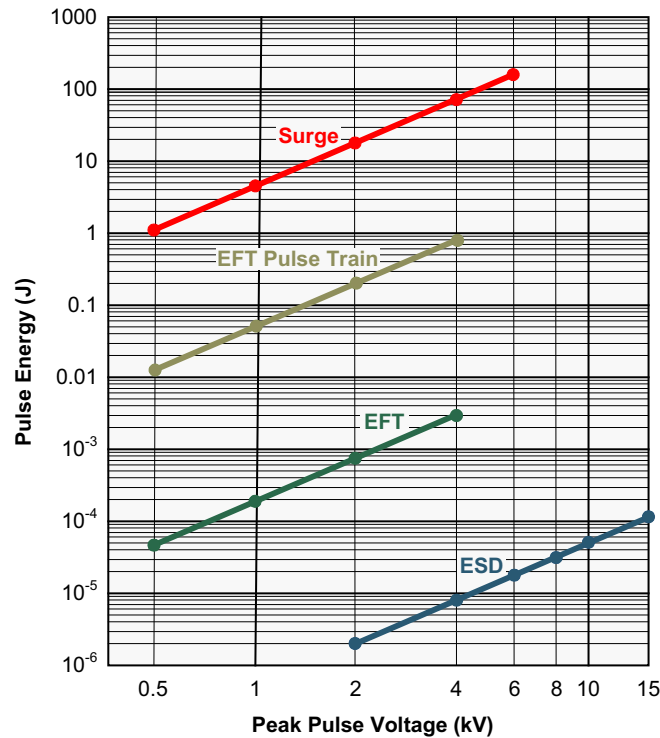


图 20. Comparison of Transient Energies

Typical Application (接下页)

9.2.2 Detailed Design Procedure

In order to protect bus nodes against high-energy transients, the implementation of external transient protection devices is necessary. 图 21 suggests a protection circuit against 1 kV surge (IEC 61000-4-5) transients. 表 3 shows the associated bill of materials.

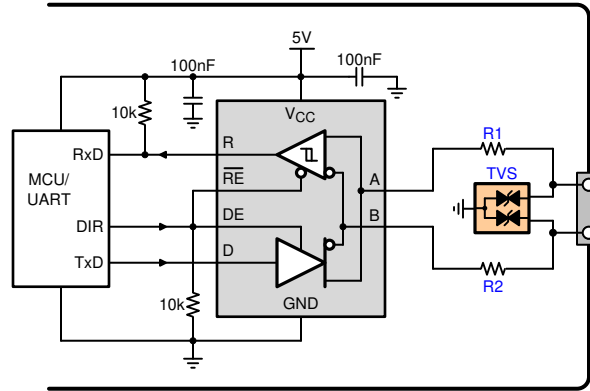


图 21. Transient Protection Against Surge Transients for Half-Duplex Devices

表 3. Bill of Materials

DEVICE	FUNCTION	ORDER NUMBER	MANUFACTURER
XCVR	RS-485 transceiver	THVD1520	TI
R1	10-Ω, pulse-proof thick-film resistor	CRCW0603010RJNEAHP	Vishay
R2			
TVS	Bidirectional 400-W transient suppressor	CDSOT23-SM712	Bourns

9.2.3 Application Curves



图 22. Waveforms at 10 Mbps Operation, PRBS7 Data Pattern

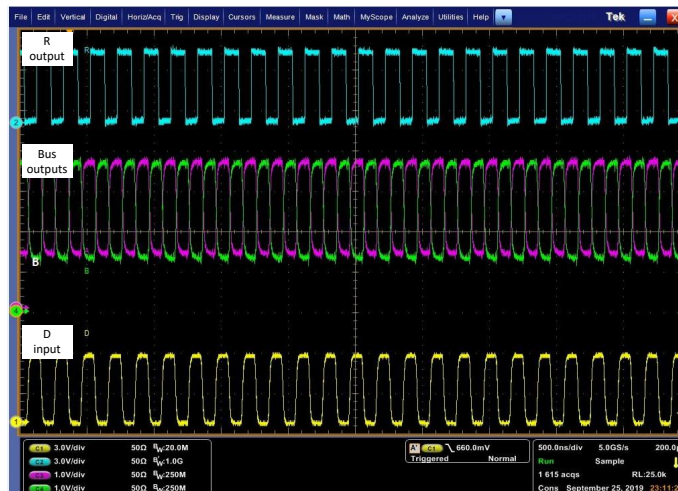


图 23. Waveforms at 10 Mbps Operation, Clock Data Pattern

10 Power Supply Recommendations

To ensure reliable operation at all data rates and supply voltages, each supply should be decoupled with a 100 nF ceramic capacitor located as close to the supply pins as possible. This helps to reduce supply voltage ripple present on the outputs of switched-mode power supplies and also helps to compensate for the resistance and inductance of the PCB power planes.

12 器件和文档支持

12.1 器件支持

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这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
THVD1520DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1520

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THVD1520DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

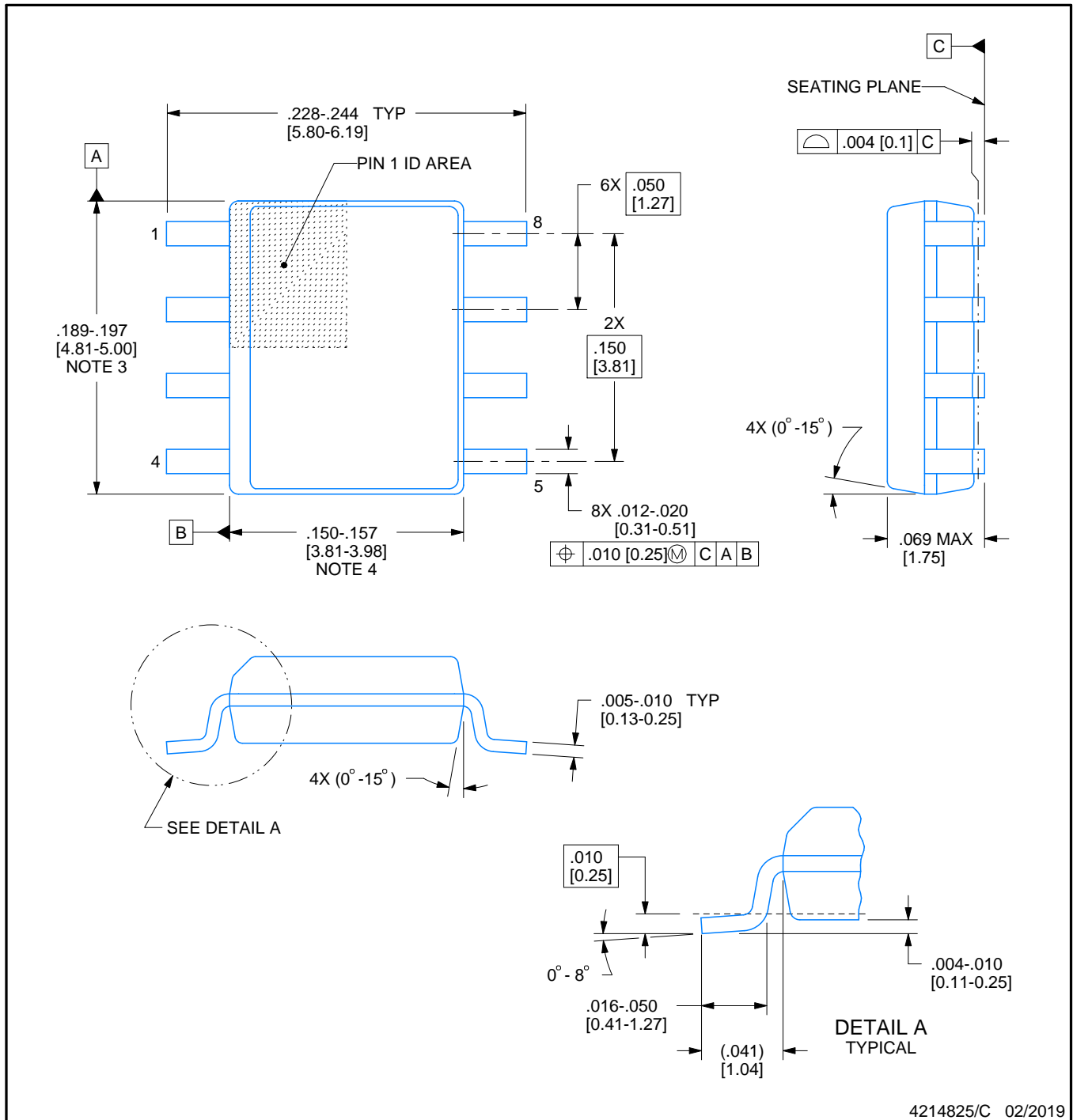


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THVD1520DR	SOIC	D	8	2500	356.0	356.0	35.0

D0008A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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